

## **INFORMATION DISCLOSURE CITATION**

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KOCHERGIN et al.

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10 of 10

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## **U.S. PATENT DOCUMENTS**

## **FOREIGN PATENT DOCUMENTS**

## **TRANSLATION**

**OTHER DOCUMENTS (including Author, Title, Date, Pertinent pages, etc.)**

*CH* H H. Föll et al., "Porous III-V compound semiconductors: formation, properties, and comparison to silicon", *Phys. Stat. Sol. A*, **197** (1), pp. 61-70 (2003)

*HE* S. Langa et al., *Phys. Stat. Sol. (A)*, **195** (3), "Electrochemical pore etching in Ge," R4–R6 (2003)

*HK* Macleod H.A., *Thin-Film Optical Filters*, 3rd ed., Institute of Physics Publishing, 2001

\*Examiner

*[Signature]*

**Date Considered**

8/1/06

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.